

## Description

The PESDNC2FD5VBN protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.

## Feature

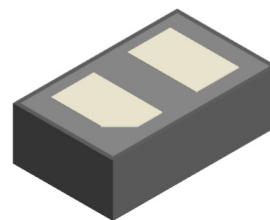
- 45W peak pulse power per line ( $t_P = 8/20\mu s$ )
- DFN1006-2L package
- Replacement for MLV (0402)
- Bidirectional configurations
- Response time is typically  $< 1ns$
- Low clamping voltage
- Transient protection for data lines to  
IEC61000-4-2(ESD)  $\pm 25KV$ (air),  $\pm 25KV$ (contact);  
IEC61000-4-4 (EFT) 40A (5/50ns)

## Applications

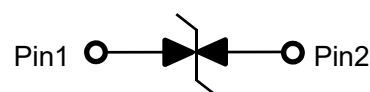
- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

## Mechanical Characteristics

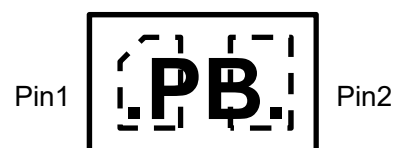
- Qualified max reflow temperature:  $260^{\circ}C$
- Device meets MSL 1 requirements
- RoHS compliant



**DFN1006-2L(Bottom View)**



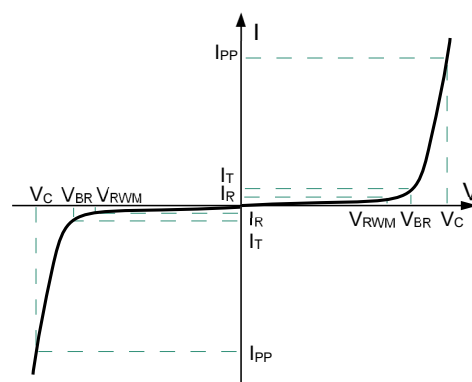
**Circuit Diagram**



**Marking (Top View)**

## Electronics Parameter Definitions

Symbol	Parameter
$V_{RWM}$	Peak Reverse Working Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$P_{PP}$	Peak Pulse Power



## Electrical characteristics at @25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse Working Voltage	$V_{RWM}$				5	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	5.6	7.0	7.8	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5\text{V}$			1.0	$\mu\text{A}$
Clamping Voltage <sup>1)</sup>	$V_{CL}$	$I_{PP} = 16\text{A}$ , $t_p = 100\text{ns}$		9.3		V
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A}$ ,		7.5	8.0	V
Clamping Voltage <sup>2)</sup>	$V_C$	$I_{PP} = 3\text{A}$ , $t_p = 8/20\mu\text{s}$		8.0	9.0	V
Clamping Voltage <sup>2)</sup>	$V_C$	$I_{PP} = 5.5\text{A}$ , $t_p = 8/20\mu\text{s}$		8.5	9.5	V
Junction Capacitance	$C_J$	$V_R = 0\text{V}$ , $f = 1\text{MHz}$		15	20	pF

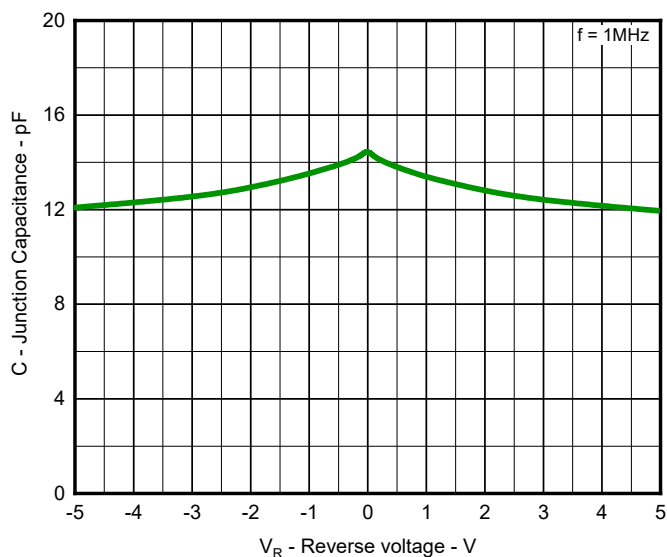
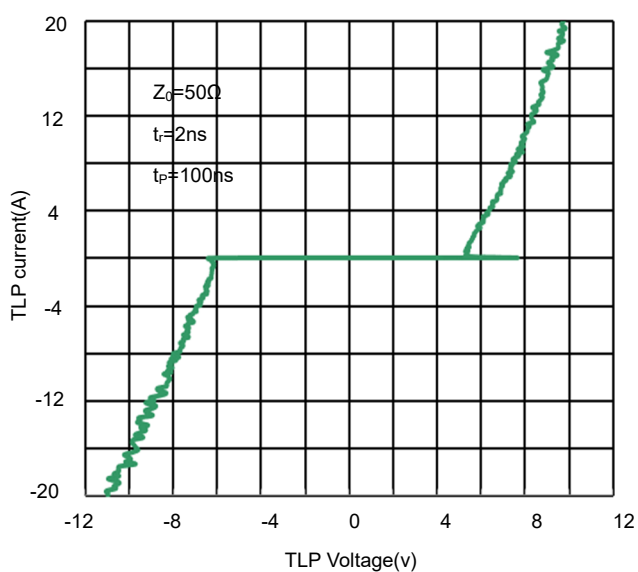
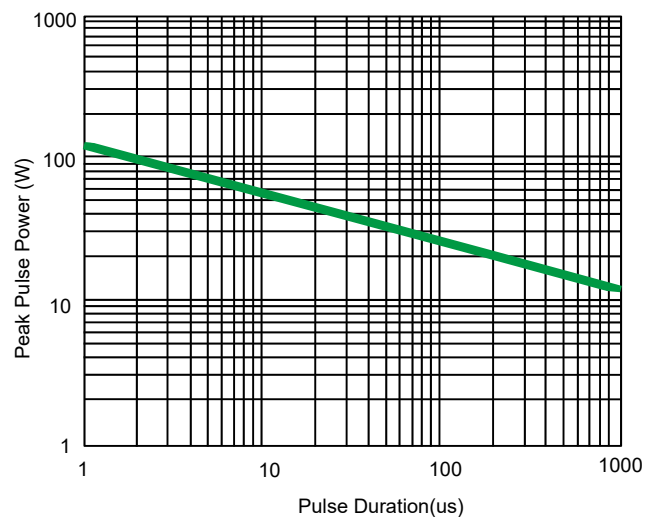
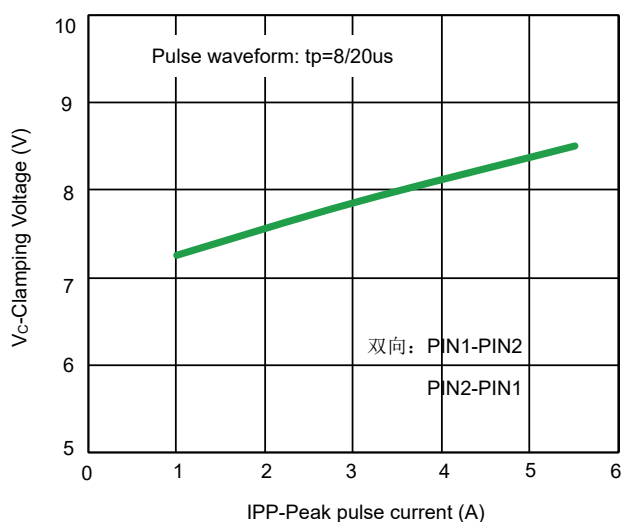
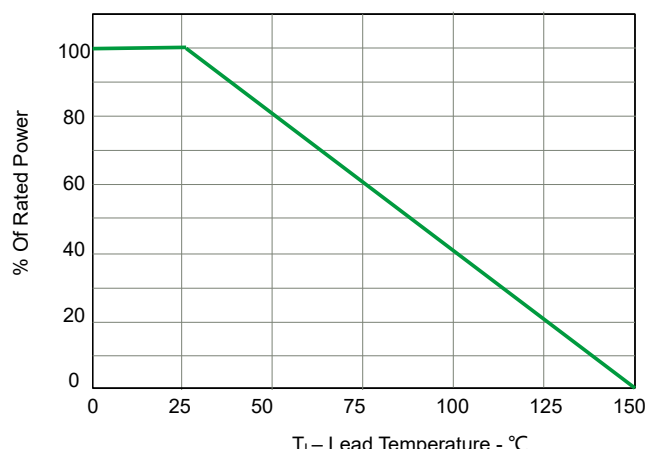
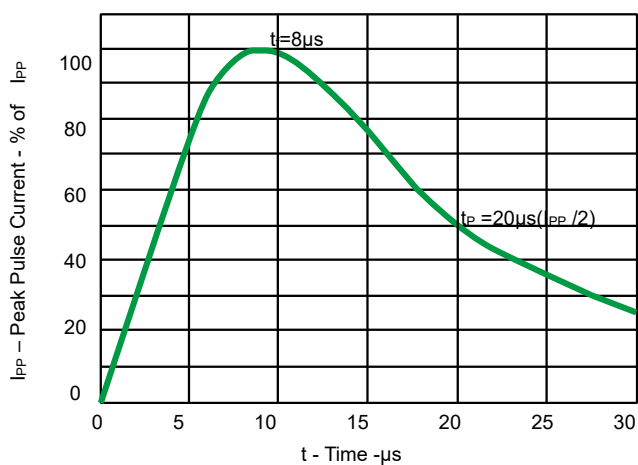
## Notes:

1. TLP parameter:  $Z_0 = 50\Omega$ ,  $t_p = 100\text{ns}$ ,  $t_r = 2\text{ns}$ , averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A.
2. Non-repetitive current pulse, according to IEC61000-4-5.

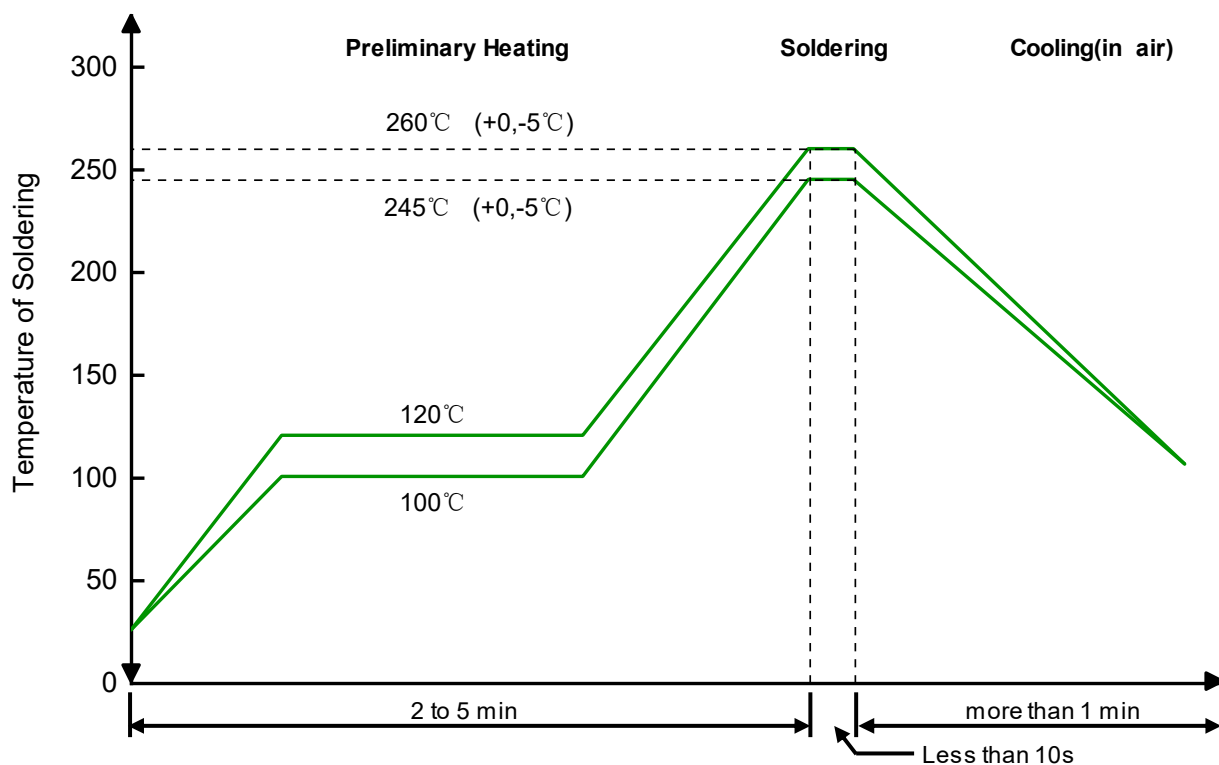
## Absolute maximum rating@25°C

Rating	Symbol	Value	Unit
Peak Pulse Power ( $t_p = 8/20\mu\text{s}$ )	$P_{pp}$	45	W
Peak Pulse Current ( $t_p = 8/20\mu\text{s}$ )	$I_{pp}$	5.5	A
Operating Temperature	$T_J$	-55 to 150	°C
Storage Temperature	$T_{STG}$	-55 to 150	°C
ESD Protection-Contact Discharge	$V_{ESD}$	$\pm 25$	kV
ESD Protection-Air Discharge	$V_{ESD}$	$\pm 25$	kV

## Typical Characteristics



## Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

## PCB Design

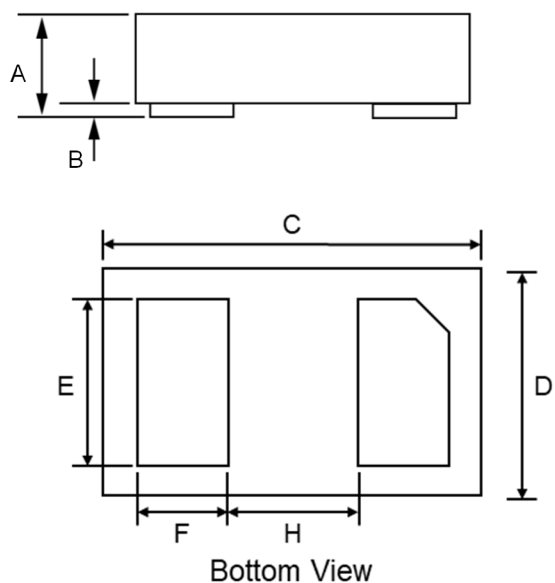
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

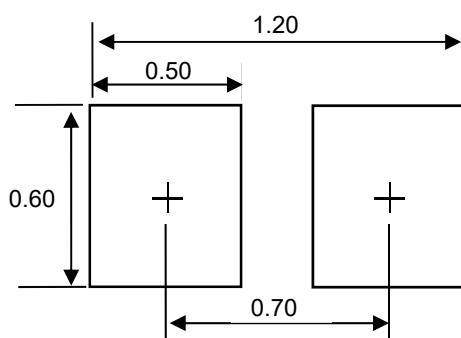
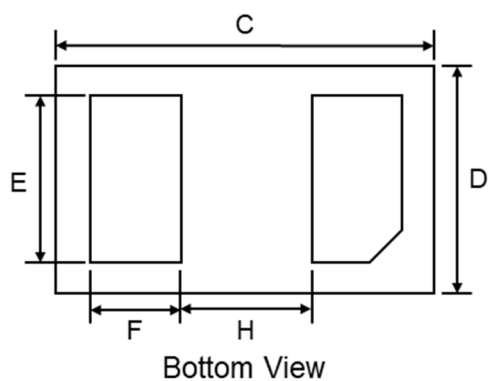
## Ordering information

Device	Package	Reel Size	MPQ
PESDNC2FD5VBN	DFN1006-2L (Pb-Free)	7"	10000 / Tape & Reel

## Product dimension (DFN1006-2L)



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	0.40	0.55	0.016	0.022
B	0.00	0.05	0.000	0.002
C	0.90	1.10	0.035	0.043
D	0.55	0.65	0.022	0.026
E	0.35	0.55	0.014	0.022
F	0.15	0.30	0.006	0.012
H	0.40 Typ.		0.015 Typ.	



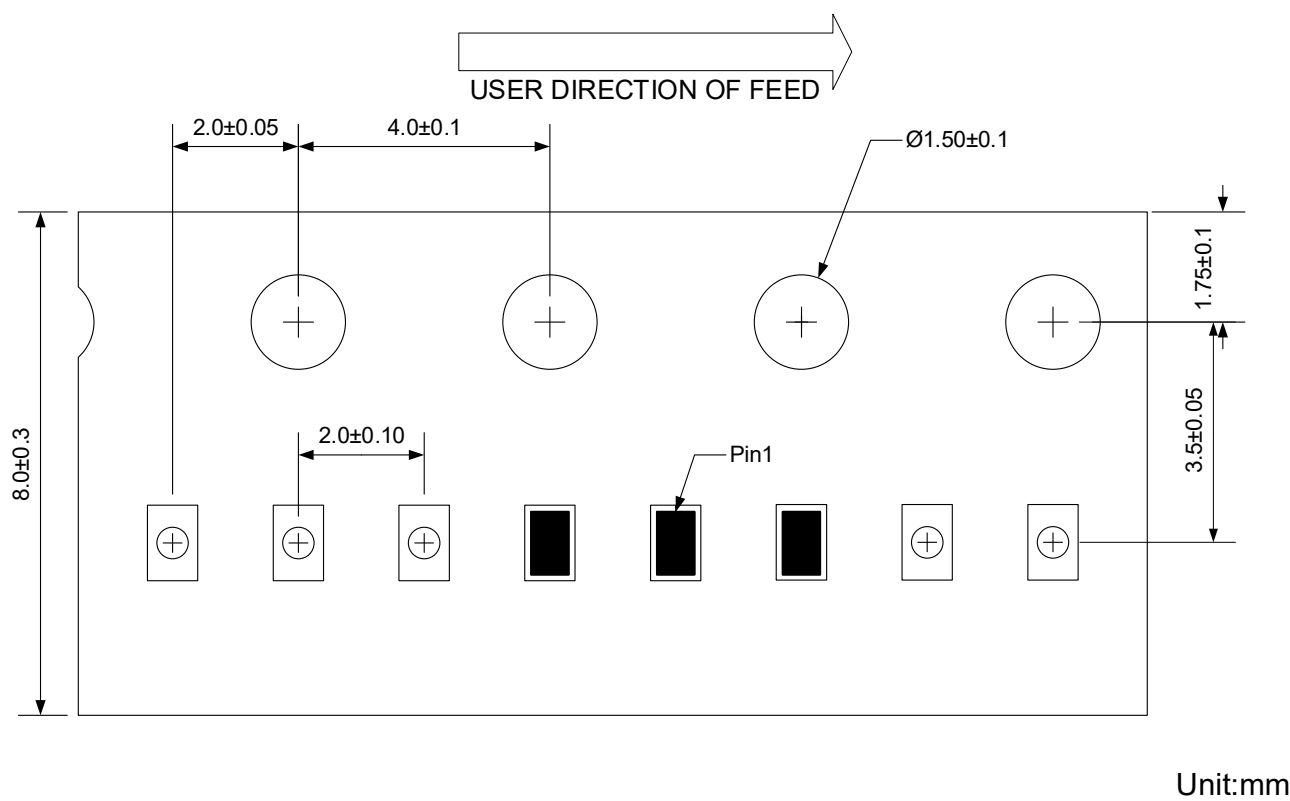
Unit:mm

Suggested PCB Layout


## Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

## Load with information




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